

PC71 5V

High Sensitivity Type Photocoupler

* Lead forming type (1 type) and taping reel type (P type) are also available. (PC715V1/PC715VP) (Page 656)
 ** TUV (VDE0884) approved type is also available as an option.

■ Features

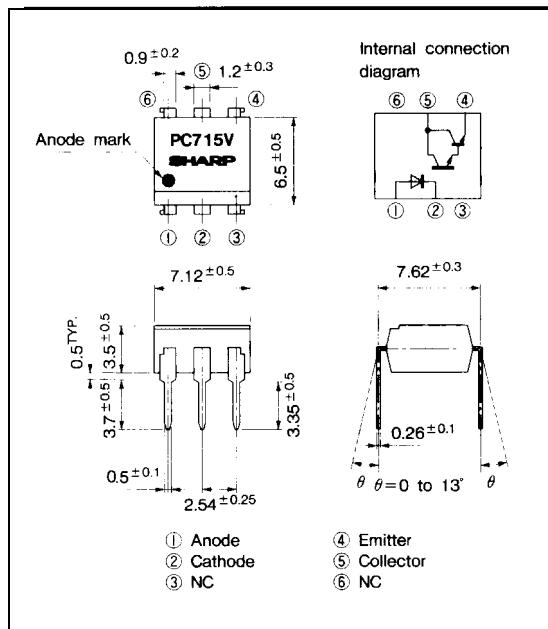
1. High current transfer ratio
(CTR : MIN. 600% at $I_F = 1\text{mA}$, $V_{CE} = 2\text{V}$)
2. High isolation voltage between input and output
($V_{iso} : 5\,000\text{V}_{rms}$)
3. Recognized by UL, file No. E64380

■ Applications

1. System appliances, measuring instruments
2. Copiers, automatic vending machines
3. Medical instruments
4. Signal transmission between circuits of different potentials and impedances

■ Outline Dimensions

(Unit : mm)



■ Absolute Maximum Ratings

(Ta = 25°C)

	Parameter	Symbol	Rating	unit
Input	Forward current	I_F	50	mA
	* ¹ Peak forward current	I_{FM}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation	P	70	mW
Output	Collector -emitter voltage	V_{CEO}	35	v
	Emitter -collector voltage	V_{ECO}	6	V
	Collector current	I_C	80	mA
	Collector power dissipation	P_C	150	mW
	Total power dissipation	P_{T}	170	mW
	* ² Isolation voltage	V_{iso}	5 000	Vm
	Operating temperature	T_{opr}	-25 to +100	°C
	Storage temperature	T_{stg}	-40 to +125	°C
	Soldering temperature	T_{sol}	260	°C

*¹Pulse width ≤ 100 μs, Duty ratio = 0.001

*²40 to 60%, RH, AC fo

*³For 10 seconds

■ Electro-optical Characteristics

(Ta = 25°C)

Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input	Forward voltage	V _F	I _F = 10mA	—	1.2	1.4	v
	Peak forward voltage	V _{FM}	I _{FM} = 0.5A	—	—	3.0	v
	Reverse current	I _R	V _R = 4V	—	—	10	μA
	Terminal capacitance	C _t	V = 0, f = 1kHz	—	30	250	pF
Output	Collector dark current	I _{CEO}	V _{CE} = 10V, I _F = 0	—	—	10 ⁻⁶	A
Transfer characteristics	Current transfer ratio	CTR	I _F = 1mA, V _{CE} = 2V	600	1 600	7 500	1000
	Collector-emitter saturation voltage	V _{CE(sat)}	I _F = 20mA, I _C = 5mA	—	—	1.0	v
	Isolation resistance	R _{ISO}	DC500V, 40 to 60%RH	5 × 10 ¹⁰	10 ¹¹	—	Ω
	Floating capacitance	C _f	V = 0, f = 1MHz	—	0.6	1.0	pF
	Cut off frequency	f _C	V _{CE} = 2V, I _C = 2mA, R _L = 100Ω, -3dB	—	6	—	kHz
	Response time	t _r	V _{CE} = 2V, I _C = 10mA, R _L = 100Ω	—	60	250	μs
	Fall time	t _f		—	53	250	μs

Fig. 1 Forward Current vs. Ambient Temperature

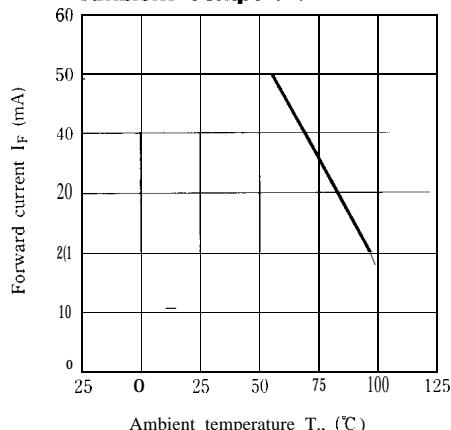


Fig. 2 Collector Power Dissipation VS. Ambient Temperature

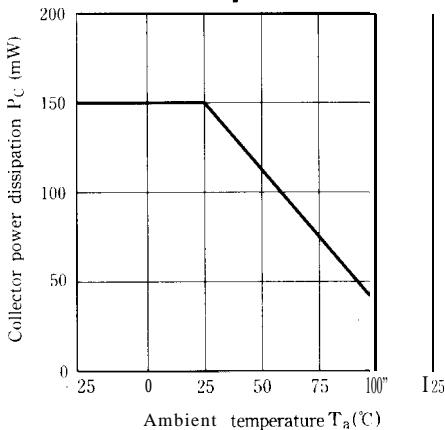


Fig. 3 Peak Forward Current vs. Duty Ratio

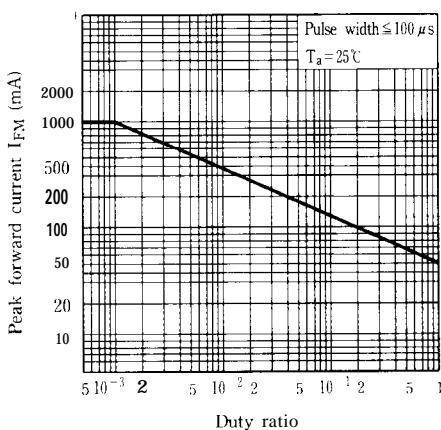


Fig. 4 Forward Current vs. Forward Voltage

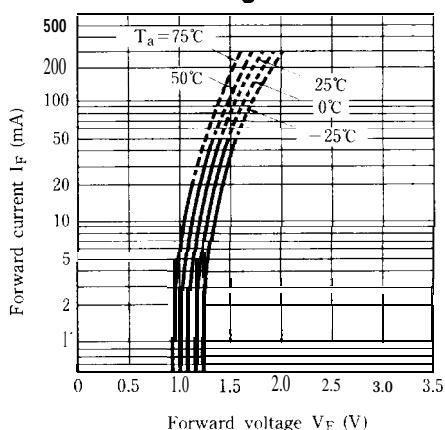


Fig. 5 Current Transfer Ratio vs. Forward Current

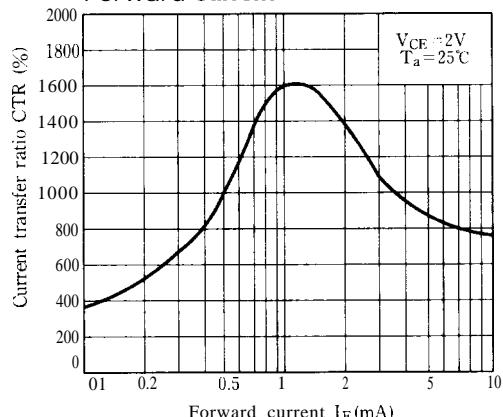


Fig. 6-a Collector Current vs. Collector-emitter Voltage

Fig. 6-b Collector Current vs. Collector-emitter Voltage

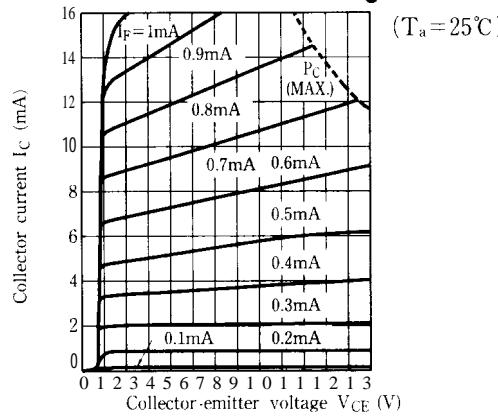


Fig. 6-b Collector Current vs. Collector-emitter Voltage

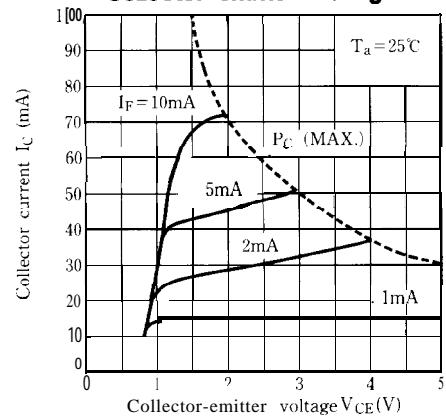


Fig. 8 Collector-emitter Saturation Voltage vs. Ambient Temperature

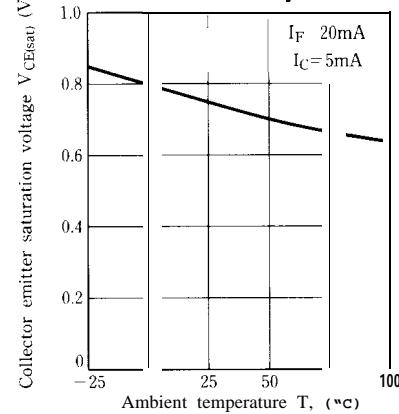


Fig. 7 Relative Current Transfer Ratio vs. Ambient Temperature

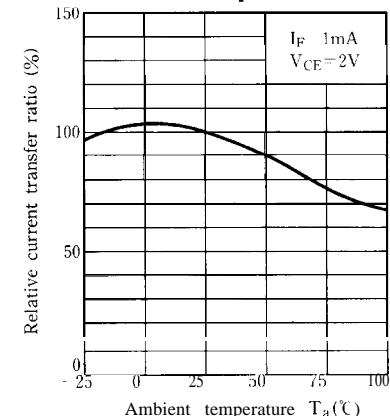


Fig. 9 Collector Dark Current vs. Ambient Temperature

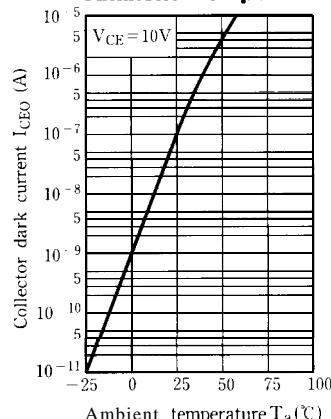
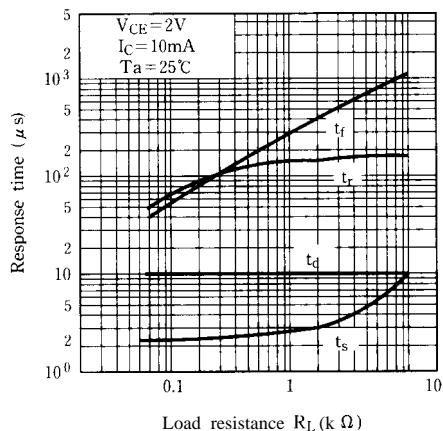
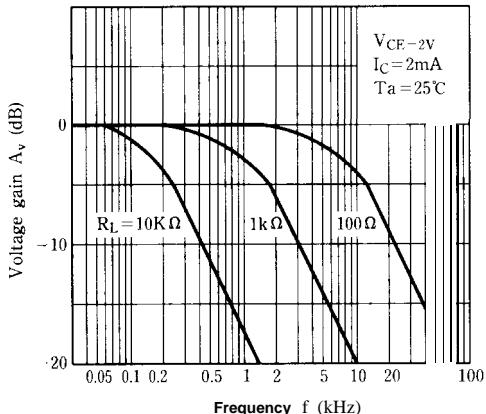
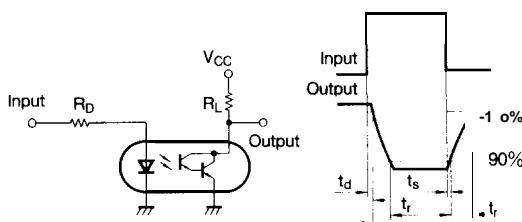
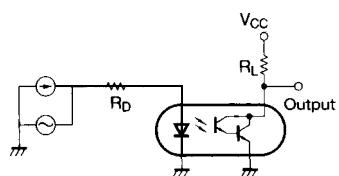


Fig.10 Response Time vs. Load Resistance**Fig.11 Frequency Response****Test Circuit for Response Time****Test Circuit for Frequency Response**

- Please refer to the chapter “Precautions for Use” (Page 78 to 93)